AUTOMOTIVE GRADE

International

Features

- Advanced Process Technology
- Ultra Low On-Resistance
- Dynamic dv/dt Rating
- 175°C Operating Temperature
- Fast Switching
- Repetitive Avalanche Allowed up to Tjmax
- Lead-Free, RoHS Compliant
- Automotive Qualified *

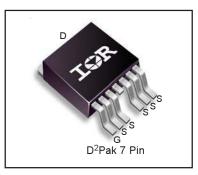
Description

Specifically designed for Automotive applications, this HEXFET[®] Power MOSFET utilizes the latest processing techniques to achieve extremely low on-resistance per silicon area. Additional features of this design are a 175°C junction operating temperature, fast switching speed and improved repetitive avalanche rating. These features combine to make this design an extremely efficient and reliable device for use in Automotive applications and a wide variety of other applications.

AUIRFS3006-7P

HEXFET[®] Power MOSFET

D	V _{DSS}	60V
	R _{DS(on)} typ.	1.5m Ω
┝┥┓ 本)	max.	2.1m Ω
┥┝╧┛╽	ID (Silicon Limited)	293A ①
s	ID (Package Limited)	240A



G	D	S
Gate	Drain	Source

Absolute Maximum Ratings

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only; and functional operation of the device at these or any other condition beyond those indicated in the specifications is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability. The thermal resistance and power dissipation ratings are measured under board mounted and still air conditions. Ambient temperature (T_A) is 25°C, unless otherwise specified.

Symbol	Parameter	Max.	Units
$I_D @ T_C = 25^{\circ}C$	Continuous Drain Current, V _{GS} @ 10V (Silicon Limited)	293 ①	
I _D @ T _C = 100°C	Continuous Drain Current, V _{GS} @ 10V (Silicon Limited)	207①	
I _D @ T _C = 25°C	Continuous Drain Current, V _{GS} @ 10V (Package Limited)	240	
I _{DM}	Pulsed Drain Current ②	1172	
$P_{D} @ T_{C} = 25^{\circ}C$	Maximum Power Dissipation	375	W
	Linear Derating Factor	2.5	W/°C
V _{GS}	Gate-to-Source Voltage	± 20	V
E _{AS}	Single Pulse Avalanche Energy (Thermally Limited) 3	303	mJ
I _{AR}	Avalanche Current [©]	See Fig. 14, 15, 22a, 22b,	A
E _{AR}	Repetitive Avalanche Energy ②		mJ
dv/dt	Peak Diode Recovery ④	11	V/ns
TJ	Operating Junction and	-55 to + 175	
T _{STG}	Storage Temperature Range		
	Soldering Temperature, for 10 seconds	300	
	(1.6mm from case)		

Thermal Resistance

Symbol	Parameter	Тур.	Max.	Units
$R_{\theta JC}$	Junction-to-Case 3		0.4	°C/W
R _{0JA}	Junction-to-Ambient (PCB Mount) ®		40	C/ W

HEXFET[®] is a registered trademark of International Rectifier. *Qualification standards can be found at http://www.irf.com/

Static Electrical Characteristics @ T_J = 25°C (unless otherwise specified)

Symbol	Parameter	Min.	Тур.	Max.	Units	Conditions	
V _{(BR)DSS}	Drain-to-Source Breakdown Voltage	60			V	$V_{GS} = 0V, I_{D} = 250\mu A$	
$\Delta V_{(BR)DSS} / \Delta T_J$	Breakdown Voltage Temp. Coefficient		0.07		V/°C	Reference to 25°C, I _D = 5mA [®]	
R _{DS(on)}	Static Drain-to-Source On-Resistance		1.5	2.1	mΩ	V _{GS} = 10V, I _D = 168A ⑤	
V _{GS(th)}	Gate Threshold Voltage	2.0		4.0	V	$V_{DS} = V_{GS}, I_D = 250 \mu A$	
gfs	Forward Transconductance	290			S	$V_{DS} = 25V, I_{D} = 168A$	
R _{G(int)}	Internal Gate Resistance		2.1		Ω		
I _{DSS}	Drain-to-Source Leakage Current			20		$V_{DS} = 60V, V_{GS} = 0V$	
				250	μA	$V_{DS} = 60V, V_{GS} = 0V, T_{J} = 125^{\circ}C$	
I _{GSS}	Gate-to-Source Forward Leakage			100		V _{GS} = 20V	
	Gate-to-Source Reverse Leakage			-100	nA	V _{GS} = -20V	
Dynamic Ele	ectrical Characteristics @ T _J = 25°C (unless	other	wises	specifi	ed)		
Symbol	Parameter	Min.	Тур.	Max.	Units	Conditions	
Q _g	Total Gate Charge		200	300		I _D = 168A	
Q _{gs}	Gate-to-Source Charge		37			V _{DS} = 30V	
Q _{gd}	Gate-to-Drain ("Miller") Charge		60		nC	$V_{GS} = 10V$ (5)	
Q _{sync}	Total Gate Charge Sync. (Q _q - Q _{qd})		140			$I_D = 168A, V_{DS} = 0V, V_{GS} = 10V$	
t _{d(on)}	Turn-On Delay Time		14			V _{DD} = 39V	
t _r	Rise Time		61			$I_{\rm D} = 168A$	
t _{d(off)}	Turn-Off Delay Time		118		ns	$R_{G} = 2.7\Omega$	
t _f	Fall Time		69			V _{GS} = 10V ⑤	
C _{iss}	Input Capacitance		8850			$V_{GS} = 0V$	
C _{oss}	Output Capacitance		1007			$V_{DS} = 50V$	
C _{rss}	Reverse Transfer Capacitance		525		рF	f = 1.0MHz (See Fig 5)	
	Effective Output Capacitance (Energy Related)		1460		'	V _{GS} = 0V, V _{DS} = 0V to 48V ⑦(See Fig 11)	
C _{oss} eff. (TR)	Effective Output Capacitance (Time Related) ©		1915			$V_{GS} = 0V, V_{DS} = 0V \text{ to } 48V \text{ (6)}$	
	racteristics						
Symbol	Parameter	Min.	Тур.	Max.	Units	Conditions	
I _S	Continuous Source Current		- ,			MOSFET symbol	
0	(Body Diode)			293 ①		showing the	
I _{SM}	Pulsed Source Current				A	integral reverse	
SIM .	(Body Diode)			1172		p-n junction diode.	
V _{SD}	Diode Forward Voltage			1.3	V	$T_J = 25^{\circ}C, I_S = 168A, V_{GS} = 0V$ (5)	
t _{rr}	Reverse Recovery Time		44	_		$T_J = 25^{\circ}C$ $V_B = 51V$,	
	· · · · · · · · · ·		48		ns	$T_{\rm J} = 125^{\circ}C$ $I_{\rm F} = 168A$	
	Deverse Desevery Charge		51			T _J = 25°C di/dt = 100A/µs ⑤	
Q _{rr}	Reverse Recovery Charge						
Q _{rr}	Reverse Recovery Charge				nC	$T_1 = 125^{\circ}C$	
Q _{rr} I _{BBM}	Reverse Recovery Current		62 2.03		nC A	$\overline{T_{J}} = 125^{\circ}C$ $\overline{T_{J}} = 25^{\circ}C$	

Notes:

- ① Calcuted continuous current based on maximum allowable junction temperature Bond wire current limit is 240A. Note that current limitation arising from heating of the device leds may occur with some lead mounting arrangements.
- ② Repetitive rating; pulse width limited by max. junction temperature.
- (3) Limited by T_{Jmax} , starting $T_J = 25^{\circ}C$, L = 0.021 mH
- R_G = 25 $\Omega,\,I_{AS}$ = 168A, V_{GS} =10V. Part not recommended for use above this value .
- $\label{eq:ISD} \textcircled{0.5mu}{0.5mu} I_{SD} \leq 168A, \ di/dt \leq 1410 \ A/\mu s, \ V_{DD} \leq V_{(BR)DSS}, \ T_J \leq 175^{\circ}C.$

- (5) Pulse width \leq 400µs; duty cycle \leq 2%.
- 6 C_{oss} eff. (TR) is a fixed capacitance that gives the same charging time as C_{oss} while V_{DS} is rising from 0 to 80% V_{DSS}.
- \odot C_{oss} eff. (ER) is a fixed capacitance that gives the same energy as C_{oss} while V_{DS} is rising from 0 to 80% V_{DSS}.
- ⑧ When mounted on 1" square PCB (FR-4 or G-10 Material). For recommended footprint and soldering techniquea refer to applocation note # AN-994 echniques refer to application note #AN-994.
- $\circledast~\mathsf{R}_{\theta} \, \text{is measured at } \mathsf{T}_J \, \text{approximately 90°C}.$
- 0 $\mathsf{R}_{\theta JC}$ value shown is at time zero.

Qualification Information[†]

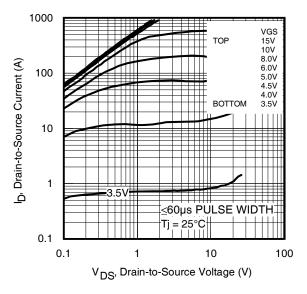
			Automotive			
			(per AEC-Q101) ^{††}			
Qualification Level		Comments: This part number(s) passed Automotive qualification. IR's Industrial and Consumer qualification level is granted by extension of the higher Automotive level.				
Moisture Sensiti	Moisture Sensitivity Level		D ² Pak 7 Pin MSL1			
	Machine Model		Class M4 (+/- 800V) ^{†††}			
			AEC-Q101-002			
	Human Body Model		Class H3A (+/- 6000V) ^{†††}			
ESD			AEC-Q101-001			
	Charged Device Model		Class C5 (+/- 2000V) ^{†††}			
			AEC-Q101-005			
RoHS Compliant			Yes			

† Qualification standards can be found at International Rectifier's web site: http://www.irf.com/

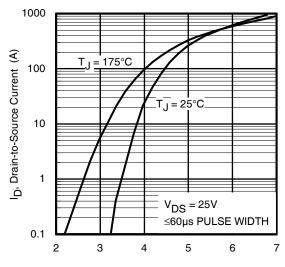
†† Exceptions (if any) to AEC-Q101 requirements are noted in the qualification report.

††† Highest passing voltage.

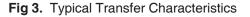
International **TOR** Rectifier







V_{GS}, Gate-to-Source Voltage (V)



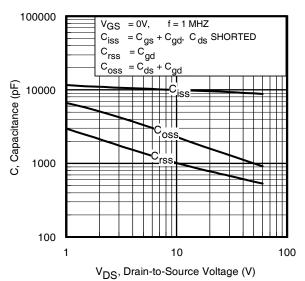


Fig 5. Typical Capacitance vs. Drain-to-Source Voltage

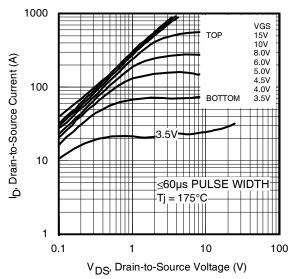
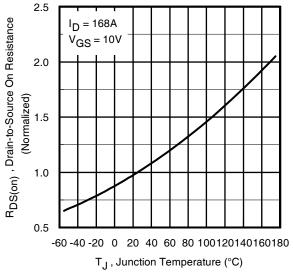


Fig 2. Typical Output Characteristics





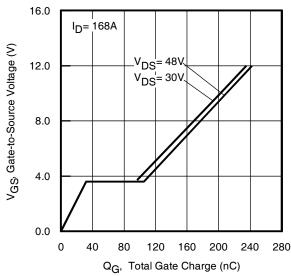


Fig 6. Typical Gate Charge vs. Gate-to-Source Voltage www.irf.com

International **IOR** Rectifier 1000 T__= 175°C I_{SD}, Reverse Drain Current (A) 100 = 25°C 10 V_{GS}'= 0V 1.0 0.4 0.0 0.8 1.2 1.6 V_{SD}, Source-to-Drain Voltage (V) Fig 7. Typical Source-Drain Diode Forward Voltage 350 Limited By Package 300 250 Drain Current (A) 200 150 ف 100 50 0 25 50 75 100 125 150 T_C , Case Temperature (°C) Fig 9. Maximum Drain Current vs. **Case Temperature** 2.5 2.0 1.5 Energy (µJ) 1.0 0.5 0.0 20 0 10 30 40

2.0

175

50

60

V_{DS.} Drain-to-Source Voltage (V) Fig 11. Typical C_{OSS} Stored Energy

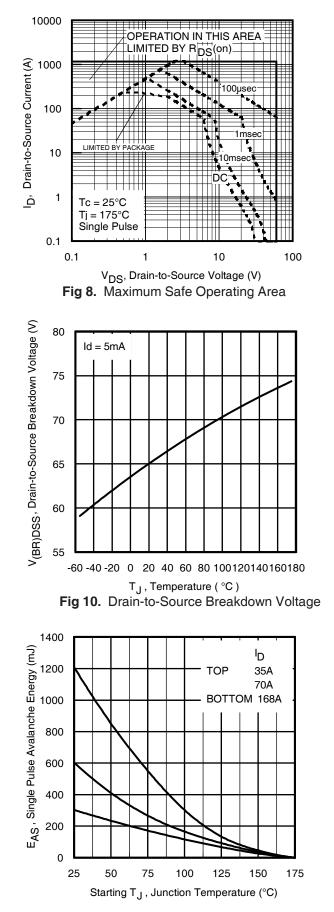


Fig 12. Maximum Avalanche Energy vs. DrainCurrent

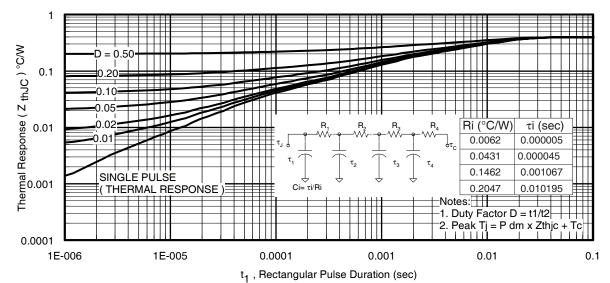


Fig 13. Maximum Effective Transient Thermal Impedance, Junction-to-Case

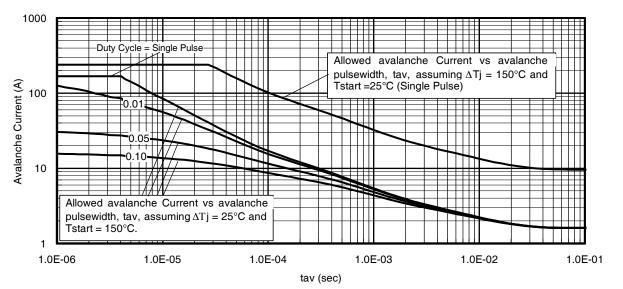


Fig 14. Typical Avalanche Current vs.Pulsewidth

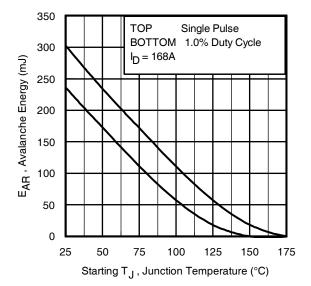


Fig 15. Maximum Avalanche Energy vs. Temperature

Notes on Repetitive Avalanche Curves , Figures 14, 15: (For further info, see AN-1005 at www.irf.com) 1. Avalanche failures assumption:

Purely a thermal phenomenon and failure occurs at a temperature far in excess of T_{jmax} . This is validated for every part type.

- 2. Safe operation in Avalanche is allowed as long asT_{imax} is not exceeded.
- 3. Equation below based on circuit and waveforms shown in Figures 16a, 16b.
- 4. P_{D (ave)} = Average power dissipation per single avalanche pulse.

5. BV = Rated breakdown voltage (1.3 factor accounts for voltage increase during avalanche).

- 6. I_{av} = Allowable avalanche current.
- 7. ΔT = Allowable rise in junction temperature, not to exceed T_{jmax} (assumed as 25°C in Figure 14, 15).
 - t_{av =} Average time in avalanche.
 - D = Duty cycle in avalanche = $t_{av} \cdot f$

Z_{thJC}(D, t_{av}) = Transient thermal resistance, see Figures 13)

$$\begin{split} P_{D~(ave)} &= 1/2~(~1.3 \cdot BV \cdot I_{av}) = \Delta T/~Z_{thJC} \\ I_{av} &= 2\Delta T/~[1.3 \cdot BV \cdot Z_{th}] \\ E_{AS~(AR)} &= P_{D~(ave)} \cdot t_{av} \end{split}$$

International **IOR** Rectifier

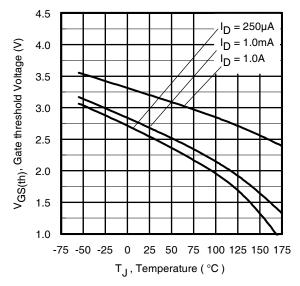
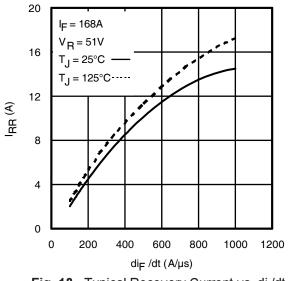
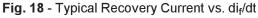
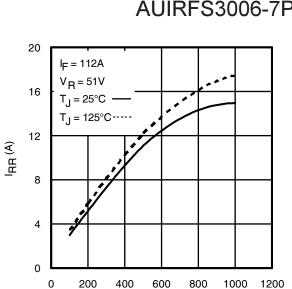


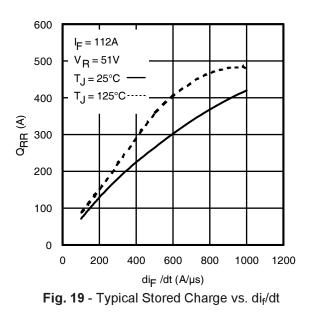
Fig 16. Threshold Voltage vs. Temperature







di_F /dt (A/µs) Fig. 17 - Typical Recovery Current vs. dif/dt



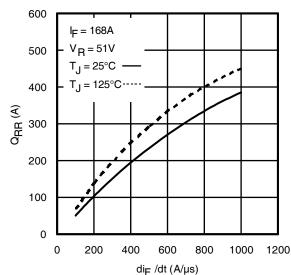
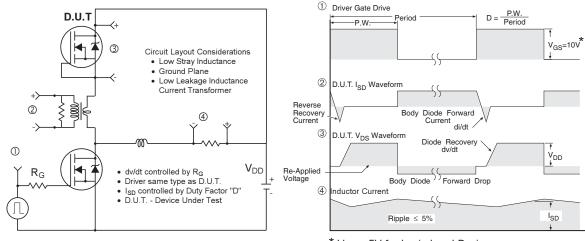
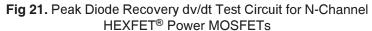


Fig. 20 - Typical Stored Charge vs. dif/dt

AUIRFS3006-7P



* V_{GS} = 5V for Logic Level Devices



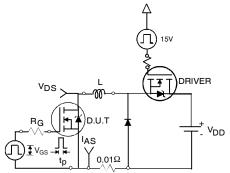


Fig 22a. Unclamped Inductive Test Circuit

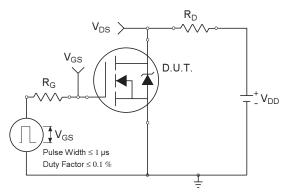


Fig 23a. Switching Time Test Circuit

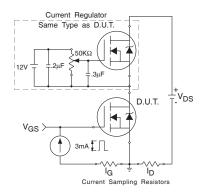


Fig 24a. Gate Charge Test Circuit

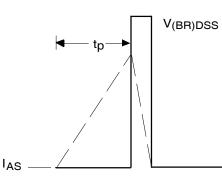


Fig 22b. Unclamped Inductive Waveforms

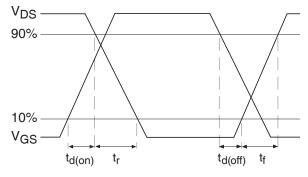


Fig 23b. Switching Time Waveforms

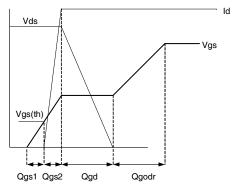
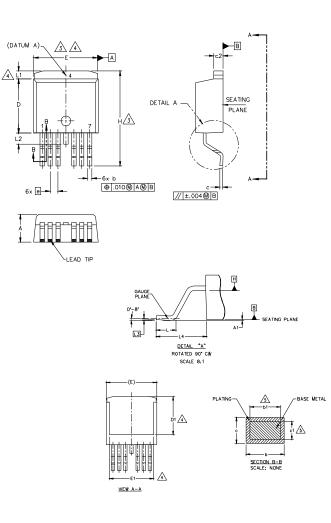


Fig 24b. Gate Charge Waveform

D²Pak (TO-263CB) 7 Long Leads Package Outline

Dimensions are shown in milimeters (inches)



S Y	DIMENSIONS				N
M B	MILLIM	IETERS INCHES			N O T E S
0 L	MIN.	MAX.	MIN.	MAX.	E S
А	4.06	4.83	.160	.190	
A1	-	0.254	-	.010	
b	0.51	0.99	.020	.036	
b1	0.51	0.89	.020	.032	5
С	0.38	0.74	.015	.029	
c1	0.38	0.58	.015	.023	5
c2	1.14	1.65	.045	.065	
D	8,38	9.65	.330	.380	3
D1	6.86	-	.270		4
Е	9.65	10.67	.380	.420	3,4
E1	6.22	-	.245		4
е	1.27	BSC	.050	BSC	
Н	14.61	15.88	.575	.625	
L	1.78	2.79	.070	.110	
L1	-	1.68	-	.066	4
L2	-	1.78	-	.070	
L3	0.25	BSC	.010	BSC	
L4	4,78	5.28	.188	.208	

NOTES:

1. DIMENSIONING AND TOLERANCING AS PER ASME Y14.5M-1994

2. DIMENSIONS ARE SHOWN IN MILLIMETERS [INCHES].

A. THERMAL PAD CONTOUR OPTIONAL WITHIN DIMENSION E, L1, D1 & E1.

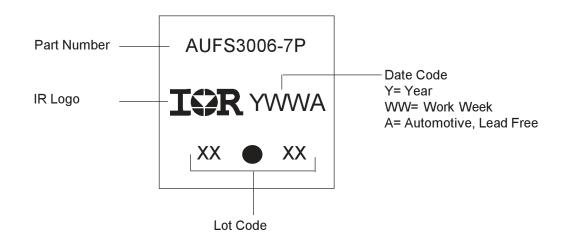
5. DIMENSION 61 AND c1 APPLY TO BASE METAL ONLY.

6. DATUM A & B TO BE DETERMINED AT DATUM PLANE H.

7. CONTROLLING DIMENSION: INCH.

8. OUTLINE CONFORMS TO JEDEC OUTLINE TO-263CB.

D²Pak - 7 Pin Part Marking Information



Note: For the most current drawing please refer to IR website at: http://www.irf.com/package/ www.irf.com

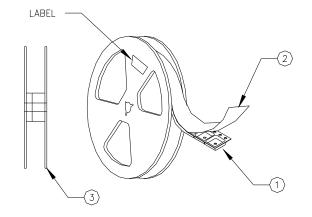
D²Pak - 7 Pin Tape and Reel

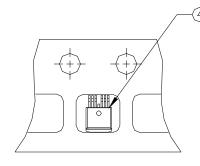
Dimensions are shown in milimeters (inches)

NOTES, TAPE & REEL, LABELLING:

- 1. TAPE AND REEL.
 - 1.1 REEL SIZE 13 INCH DIAMETER.
 - 1.2 EACH REEL CONTAINING 800 DEVICES.
 - 1.3 THERE SHALL BE A MINIMUM OF 42 SEALED POCKETS CONTAINED IN THE LEADER AND A MINIMUM OF 15 SEALED POCKETS IN THE TRAILER.
 - 1.4 PEEL STRENGTH MUST CONFORM TO THE SPEC. NO. 71-9667.
 - 1.5 PART ORIENTATION SHALL BE AS SHOWN BELOW.
 - 1.6 REEL MAY CONTAIN A MAXIMUM OF TWO UNIQUE LOT CODE/DATE CODE COMBINATIONS. REWORKED REELS MAY CONTAIN A MAXIMUM OF THREE UNIQUE LOT CODE/DATE CODE COMBINATIONS. HOWEVER, THE LOT CODES AND DATE CODES WITH THEIR RESPECTIVE QUANTITIES SHALL APPEAR ON THE BAR CODE LABEL FOR THE AFFECTED REEL.

- 2. LABELLING (REEL AND SHIPPING BAG).
 - 2.1 CUST. PART NUMBER (BAR CODE): IRFXXXXSTRL-7P
 - 2.2 CUST. PART NUMBER (TEXT CODE): IRFXXXXSTRL-7P
 - 2.3 I.R. PART NUMBER: IRFXXXXSTRL-7P
 - 2.4 QUANTITY:
 - 2.5 VENDOR CODE: IR
 - 2.6 LOT CODE:
 - 2.7 DATE CODE:





Ordering Information

Base part number	Package Type	Standard Pack		Complete Part Number
		Form	Quantity	
AUIRFS3006-7P	D2Pak 7 Pin	Tube	50	AUIRFS3006-7P
		Tape and Reel Left	800	AUIRFS3006-7TRR
		Tape and Reel Right	800	AUIRFS3006-7TRL

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